

MCT9001

DESCRIPTION

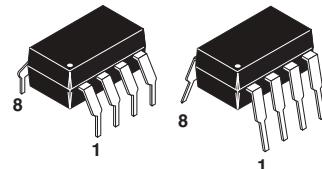
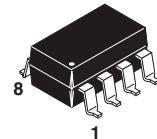
The MCT9001 Optocoupler has two channels for density applications. For four channel applications, two-packages fit into a standard 16-pin DIP socket. Each channel is an NPN silicon planar phototransistor optically coupled to a gallium arsenide infrared emitting diode.

FEATURES

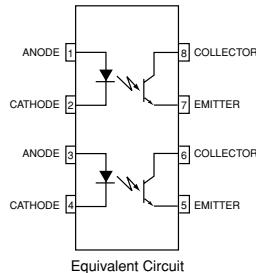
- Two isolated channels per package
- Two packages fit into a 16 lead DIP socket
- Underwriters Laboratory (U.L.) recognized File E90700

APPLICATIONS

- AC Line/Digital Logic - isolate high voltage transients
- Digital Logic/Digital Logic - Eliminate spurious grounds
- Digital Logic/AC Triac Control - isolate high voltage transients
- Twisted pair line receiver - Eliminate ground loop feedthrough
- Telephone/Telegraph line receiver - isolate high voltage transients
- High Frequency Power Supply Feedback Control - Maintain floating grounds and transients
- Relay contact monitor - isolate floating grounds and transients
- Power supply monitor - Isolate transients



SCHEMATIC



ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
EMITTER (Each channel)			
Forward Current - Continuous	I _F	60	mA
Forward Current - Peak (PW = 1μs, 300pps)	I _{F(pk)}	3	A
Reverse Voltage	V _R	5.0	V
LED Power Dissipation @ T _A = 25°C Derate above 25°C (Total Input)	P _D	100 1.1	mW mW/°C
DETECTOR (Each channel)			
Collector Current - Continuous	I _C	30	mA
Detector Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	150 1.67	mW mW/°C
TOTAL DEVICE			
Storage Temperature	T _{STG}	-55 to +150	°C
Operating Temperature	T _{OPR}	-55 to +100	°C
Lead Solder Temperature	T _{SOL}	250 for 10 sec	°C
Total Device Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	400 4.83	mW mW/°C

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)

INDIVIDUAL COMPONENT CHARACTERISTICS

Parameter	Test Conditions	Symbol	Min	Typ**	Max	Unit
EMITTER						
Input Forward Voltage	($I_F = 10 \text{ mA}$)	V_F		1.0	1.3	V
Reverse Current	($V_R = 5 \text{ V}$)	I_R			10	μA
Junction Capacitance	($V_F = 0 \text{ V}$, $f = 1 \text{ MHz}$)	C_J		50		pF
DETECTOR						
Collector-Emitter Breakdown Voltage	($I_C = 0.5 \text{ mA}$, $I_F = 0$)	BV_{CEO}	55			V
Emitter-Collector Breakdown Voltage	($I_E = 100 \mu\text{A}$, $I_F = 0$)	BV_{ECO}	7			V
Collector-Emitter Dark Current	($V_{CE} = 24 \text{ V}$, $I_F = 0$)	I_{CEO}		5	100	nA
	($V_{CE} = 24 \text{ V}$, $T_A = 85^\circ\text{C}$)				50	μA
Capacitance	($V_{CE} = 0 \text{ V}$, $f = 1 \text{ MHz}$)	C_{CE}		8		pF

TRANSFER CHARACTERISTICS

AC Characteristic	Test Conditions	Symbol	Min	Typ**	Max	Units
SWITCHING TIMES						
Non-Saturated						
Turn-on Time		t_{on}		3		
Turn-off Time		t_{off}		3		
Rise Time	($R_L = 100 \Omega$, $I_C = 2 \text{ mA}$, $V_{CC} = 10 \text{ V}$)	t_r		2.4		
Fall Time		t_f		2.4		
Saturated						
Turn-on Time	($I_F = 16 \text{ mA}$, $R_L = 1.9 \text{ k}\Omega$, $V_{CE} = 5 \text{ V}$)	t_{on}		2.4		
Turn-off Time		t_{off}		25.0		

TRANSFER CHARACTERISTICS

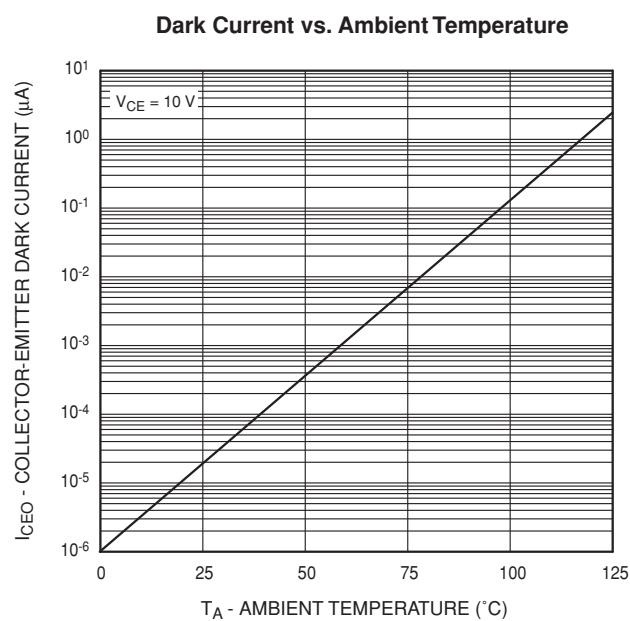
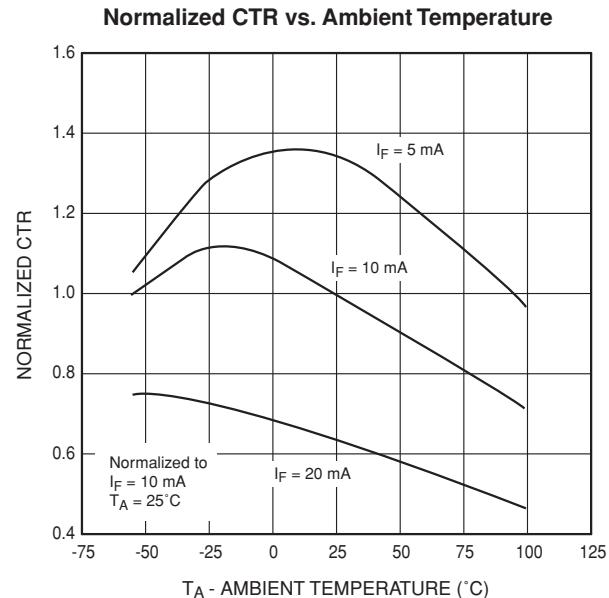
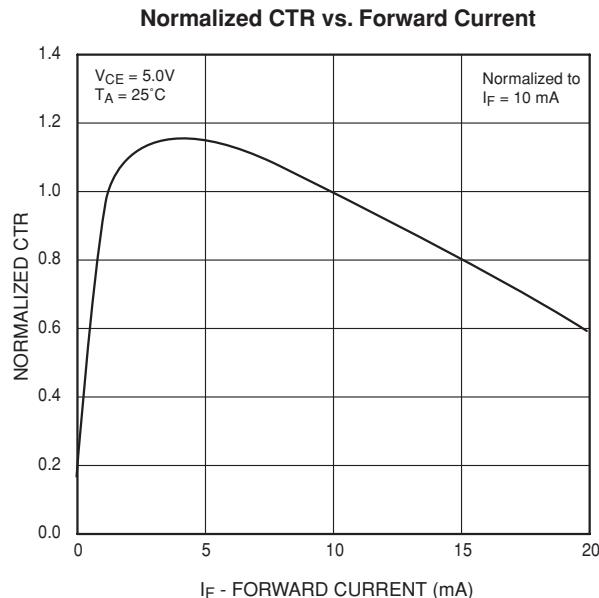
DC Characteristic	Test Conditions	Symbol	Min	Typ**	Max	Units
Current Transfer Ratio, Collector-Emitter	($I_F = 5 \text{ mA}$, $V_{CE} = 5 \text{ V}$)	CTR	50		600	%
	($I_F = 8 \text{ mA}$, $V_{CE} = 0.4 \text{ V}$)	$CTR_{(sat)}$	30			
Saturation Voltage	($I_F = 8 \text{ mA}$, $I_C = 2.4 \text{ mA}$)	$V_{CE(sat)}$			0.40	V

ISOLATION CHARACTERISTICS

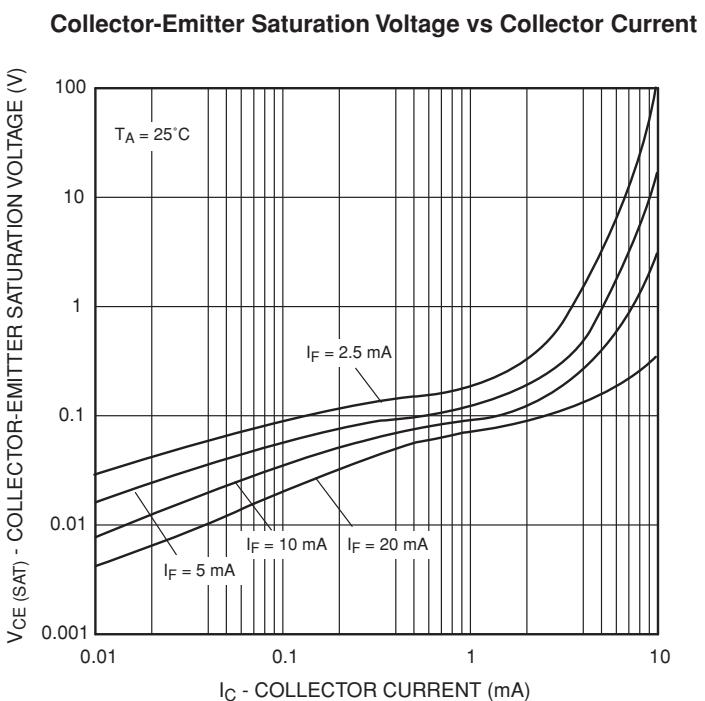
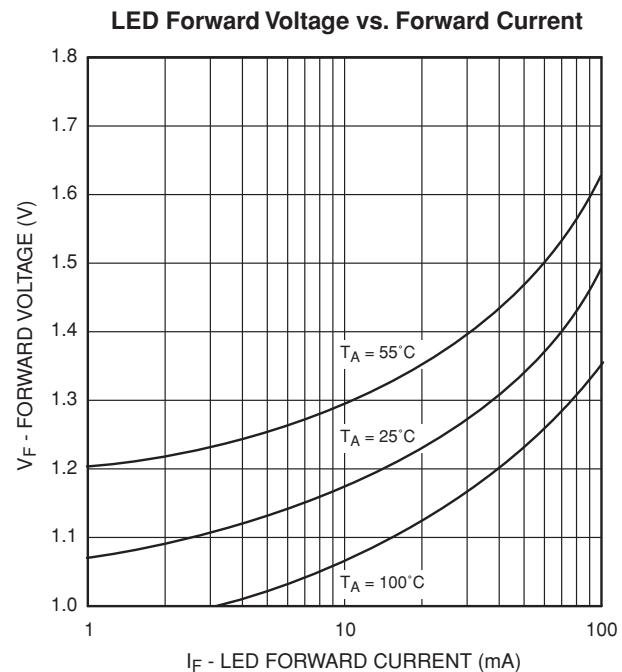
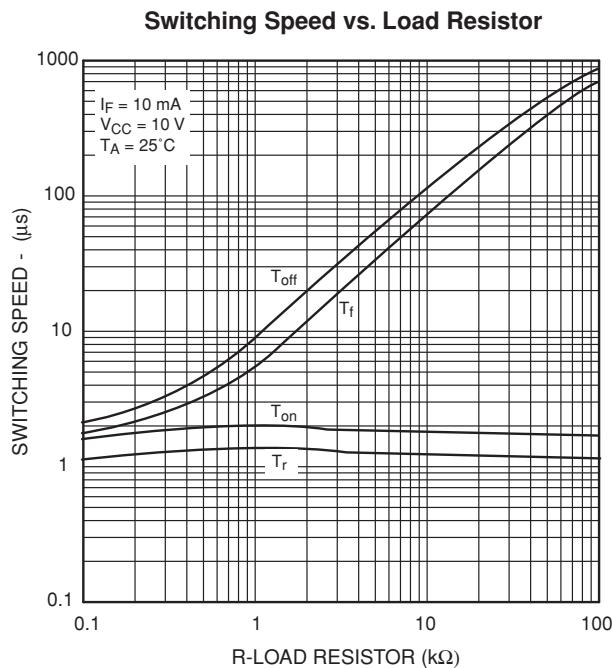
Characteristic	Test Conditions	Symbol	Min	Typ**	Max	Units
Input-Output Isolation Voltage	($I_{I-O} \leq 1 \mu\text{A}$, $t = 1 \text{ min.}$)	V_{ISO}	5300			Vac(rms)
Isolation Resistance	($V_{I-O} = 500 \text{ VDC}$)	R_{ISO}	10^{11}			Ω
Isolation Capacitance	($f = 1 \text{ MHz}$)	C_{ISO}		0.5		pf

** All typicals at $T_A = 25^\circ\text{C}$

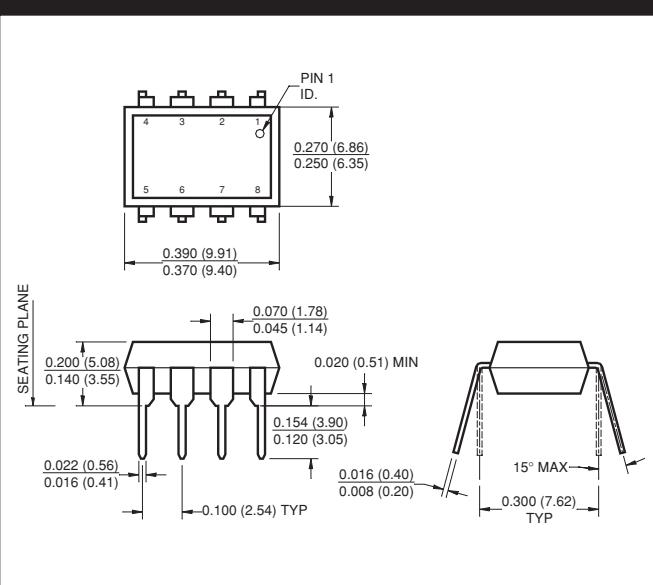
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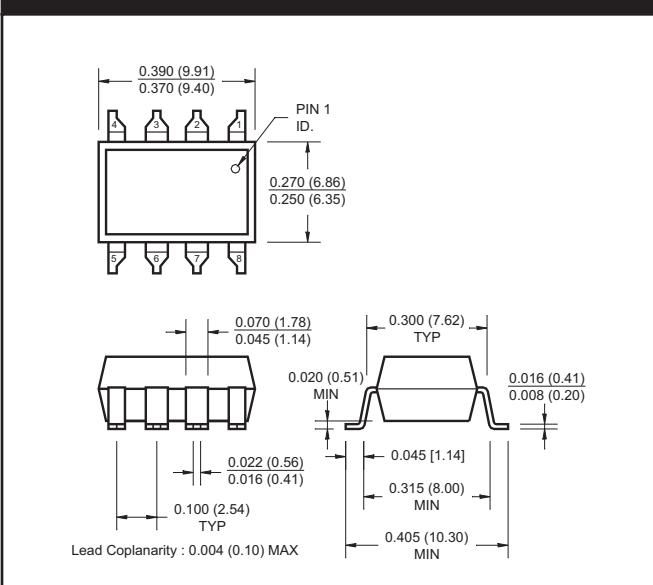
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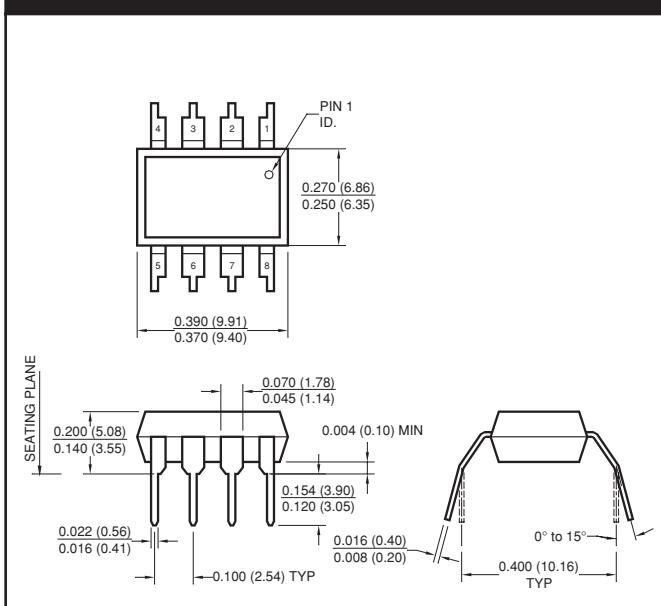
Package Dimensions (Through Hole)



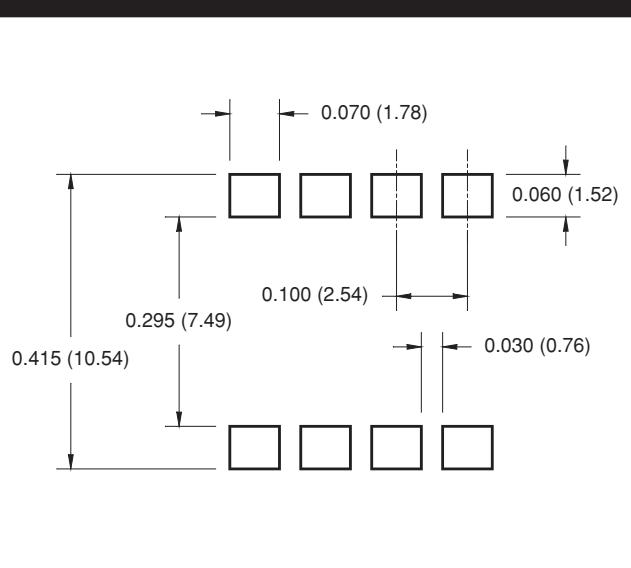
Package Dimensions (Surface Mount)



Package Dimensions (0.4"Lead Spacing)



Recommended Pad Layout for Surface Mount Leadform



NOTE

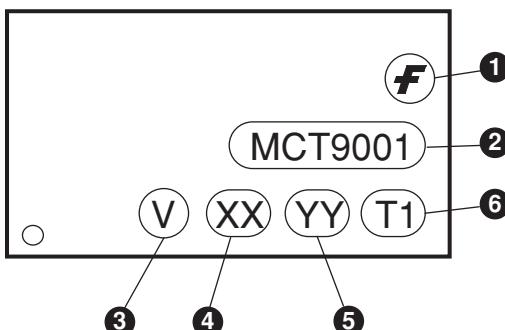
NOTE All dimensions are in inches (millimeters)

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ORDERING INFORMATION

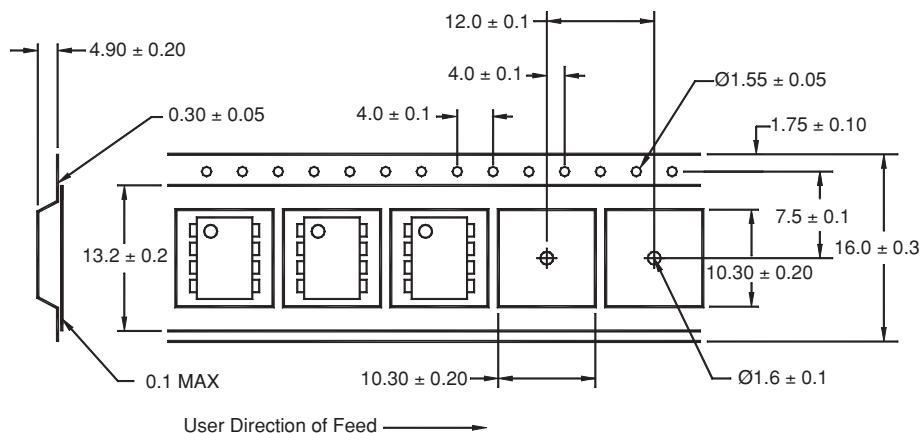
Option	Order Entry Identifier	Description
S	.S	Surface Mount Lead Bend
SD	.SD	Surface Mount; Tape and reel
W	.W	0.4" Lead Spacing

MARKING INFORMATION



Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	Two digit year code, e.g., '03'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

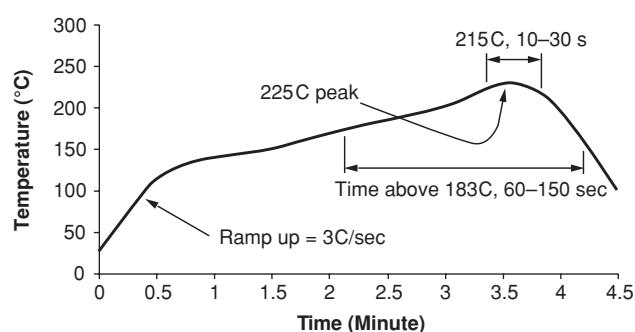
Carrier Tape Specifications



NOTE

All dimensions are in inches (millimeters)

Reflow Profile



- Peak reflow temperature: 225°C (package surface temperature)
- Time of temperature higher than 183°C for 60–150 seconds
- One time soldering reflow is recommended

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CoolFET™	FRFET™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	GlobalOptoisolator™	MicroPak™	QFET®	SuperSOT™-8
DOME™	GTO™	MICROWIRE™	QS™	SyncFET™
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FACT Quiet Series™		OPTOLOGIC®	μSerDes™	UltraFET®
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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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